

# 150U/150UR

## SILICON POWER DIODE



**NAINA**

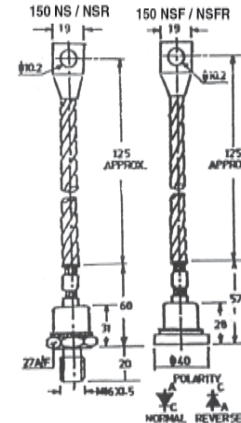
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### FEATURES

- Diffused Series
- Available in Normal & Reverse Polarity
- Industrial Grade
- Available In Avalanche Characteristic

### ELECTRICAL SPECIFICATIONS

$I_F$	Maximum Average Forward Current $T_c=125^\circ\text{C}$	150A
$V_{FM}$	Maximum peak forward voltage drop @ Rated $I_F(AV)$	1.4V
$I_{FSM}$	Maximum peak one cycle (non-rep) surge current 10 m sec	3000A
$I_{FRM}$	Maximum peak repetitive surge current	750A
$I^2t$	Maximum $I^2t$ rating (non-rep.) for 5 to 10 msec.	45,000 A <sup>2</sup> Sec



### THERMAL MECHANICAL SPECIFICATIONS

$\theta_{JC}$	Maximum thermal resistance Junction to case	0.25°C/W
$T_j$	Operating Junction Temp.	-65°C to 150°C
$T_{stg}$	Storage temperature	-65°C to 200°C
	Mounting torque (Non-lubricated threads)	2.0 M-kg min, 3.0 M-kg max
$W$	Approx, weight	150 gms.

### ELECTRICAL RATINGS

TYPE	150U/150UR	10	20	40	60	80	100	120	140	160
$V_{RRM}$	Max. repetitive peak reverse voltage (v)	100	200	400	600	800	1000	1200	1400	1600
$V_R(RMS)$	Max. R.M.S. reverse voltage (V)	70	140	280	420	560	700	840	980	1120
$V_R$	Max. D.C. Blocking Voltage (V)	100	200	400	600	800	1000	1200	1400	1600
	Recommended R.M.S. working Voltage(v)	40	80	160	240	320	400	480	560	640
$I_R(AV)$	Max. Average reverse leakage current @ $V_{RRM}$ $T_c$ 25°C (uA)	200	200	200	200	200	200	200	200	200

NAINA SEMICONDUCTOR LTD.,  
D-95, SECTOR 63, NOIDA (INDIA)  
e-mail: sales@nainasemi.com, web site: www.nainasemi.com